

TBA20-12EGWA

HIGH EFFICIENCY RED
GREEN

Features

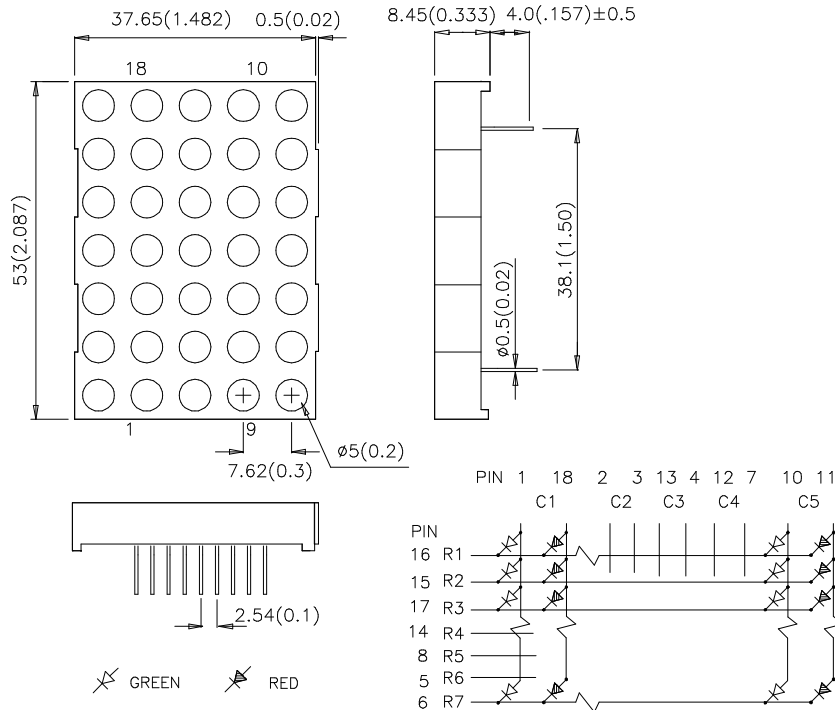
- 2.0 INCH MATRIX HEIGHT.
- DOT SIZE 5mm.
- LOW CURRENT OPERATION.
- HIGH CONTRAST AND LIGHT OUTPUT.
- STACKABLE HORIZONTALLY.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- CATEGORIZED FOR LUMINOUS INTENSITY.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE DOT.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) @ 10 mA		Description
			Min.	Typ.	
TBA20-12EGWA	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	4700	12000	Column Anode
	GREEN (GaP)		4700	16000	

Electrical / Optical Characteristics at T_A=25°C

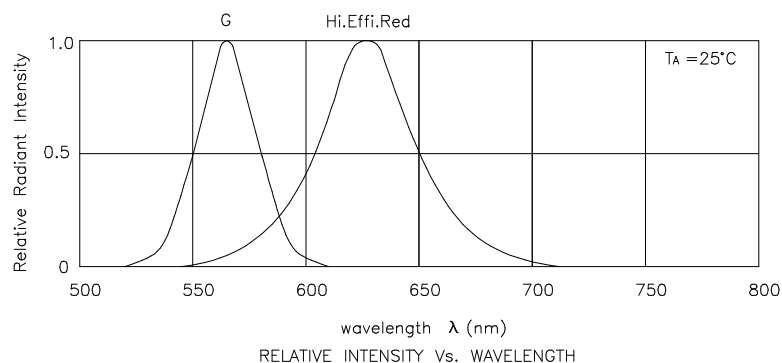
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red Green	627 565		nm	I _F =20mA
λ_D	Dominate Wavelength	High Efficiency Red Green	625 568		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	High Efficiency Red Green	45 30		nm	I _F =20mA
C	Capacitance	High Efficiency Red Green	15 15		pF	V _F =0V; f=1 MHz
V _F	Forward Voltage	High Efficiency Red Green	2.0 2.2	2.5 2.5	V	I _F =20mA
I _R	Reverse Current	All		10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	High Efficiency Red	Green	Units
Power dissipation	105	105	mW
DC Forward Current	30	25	mA
Peak Forward Current [1]	160	140	mA
Reverse Voltage	5		V
Operating/Storage Temperature	-40°C To +85°C		
Lead Solder Temperature [2]	260°C For 5 Seconds		

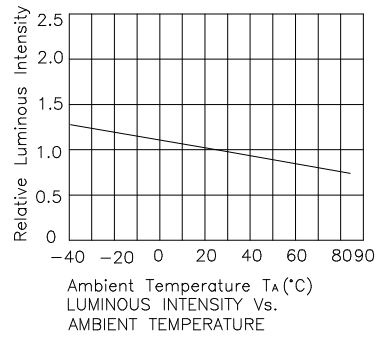
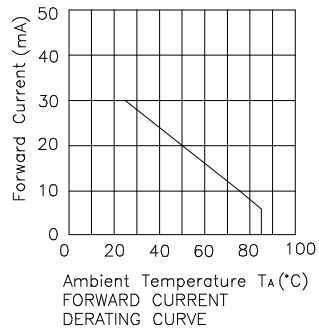
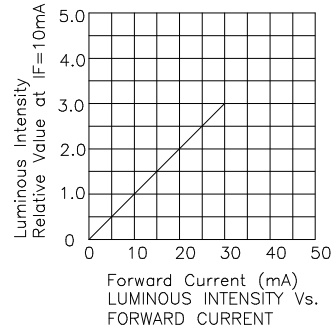
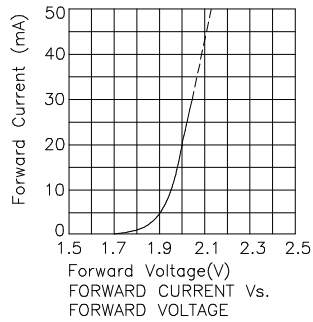
Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.



High Efficiency Red

TBA20-12EGWA



Green

